Ceramic Disc Capacitor, CH



Mechanical

Available lead code: (Unit : mm)

Lead Type	P/N (13-17) Digits	Pitch (F)	Lead Length (L)	Available Rated Voltage	Packing	Lead Configuration
Lead Style : B Straight Long Lead	B20C7	7.5 ± 1	20 Min.	1 KV	Bulk	D Maximum T Maximum Ød F

 \times Lead diameter : ϕ = 0.6 \pm 0.06 mm

* e (Coating extension on leads):

For straight lead style: 2 mm maximum when the rated voltage is 1 KV V dc

Capacitance Value vs. Rate Voltage, Product Diameter :

тс	CH (Class I, Temperature : -25°C to +85°C, TCC: 0 ±60 ppm/°C)
Rate Voltage	1 KV
Dφ	050
D Maximum (mm)	6
T Maximum (mm)	4.5
10	100

Packaging

Packaging Style

Bulk : 1,000 pieces / bag

Specification and Test Method :

Scope : This specification applies to temperature compensating ceramic disc capacitor

Test conditions : Unless otherwise specified, all tests shall be operated at the standard test conditions of temperature $5^{\circ}C$ to $35^{\circ}C$ and relative humidity 45% to 85%. When fails a test, retest be operated at the conditions of temperature $25^{\circ}C \pm 2^{\circ}C$, relative humidity of 60% to 70% and barometric pressure 860 to 1,060 mbar

Handle procedure : To avoid unexpected testing results from occurring, the tested capacitor must be kept at room temperature for at least 30 minutes and completely discharged



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Test Items:

Item	Post-Test Requirements		Testing Procedure
Appearance Structure Size	No Abnormalities		As section 3
	Between Terminals	: No Abnormalities	1 KV and Above : 200% Rated Voltage With 50 mA Maximum Charging Current for 1 to 5 s
Withstand Voltage	Between Terminal a Enclosure : No Abn		Small Metallic Balls With 1 mm Diameters Shall be Put on a Vessel and The Test Capacitor Shall be Submerged Except 2 mm From The Top of its Component Body. The Test Voltage Shall be Applied Between The Short-Circuited Terminals And The Metallic Balls. (Apply 1.3 KV dc of Rated Voltage Between Terminals and Enclosure for 1 to 5 s)
Insulation Resistance	10,000 M Ω Min.		Insulation Resistance Shall be Measured at 60 ±5 Seconds After Applied Voltage (Rated) Rated Voltage : 500 V and Above = 500 V
Capacitance	Tolerance : J : ±5%		Testing Frequency: 1 MHz ±20%Testing Voltage: 1 V rms
Operating Temperature Range	-25°C to +125°C		
Q Factor	30 pF and Above	Q ≥ 1,000	As Above Stipulation of Capacitance
	Below 30 pF	$Q \ge 400 + 20 \times C$	
Temperature Characteristic	Temperature Coeffi CH : 0 ±60 PPM/°C		According to Step 1 to 5 In Order, Measured Capacitance When Temperature Reach Balance and Temperature Coefficient Shall be Calculated on The Following Formula : PPM/°C = (C2 - C1) × 10E6 / C1 (T2-T1) STEP 1, 3, 5 : 25°C STEP 2 : -25°C STEP 4 : 85°C Note : C1 = Capacitance as Step 3 C2 = Capacitance as Step 2 or 4 T1 = Temperature as Step 3 T2 = Temperature as Step 2 or 4
	Capacitance Tolera Within ±0.2% or ±0 Whichever is Large	.05 pF,	According to Above Step 1,3 and 5, Capacitance Tolerance Shall be Calculated on the Following Formula : $\Delta C\% = (G - S) / C1$ Note : G = Greatest Capacitance as Testing Result of Step 1,3 and 5 S = Least Capacitance as Testing Result of Step 1, 3 and 5 C1 = Capacitance as Step 3
Terminal Strength	Tensile Strength : N	lo Breakdown	Wire Diameter 0.5 mm Loading Weight 0.5 Kgs, for 10 ±1 s Wire Diameter .0.6 mm Loading Weight 1 Kgs, for 10 ±1 s
	Bending Strength :	No Breakdown	Wire Diameter 0.5 mm, Loading Weight 0.25 Kgs Wire Diameter 0.6 mm, Loading Weight 0.5 Kgs (Bending Back and Forth 90° Twice)



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Test Items:

ltem	Post-Test Requirements	Testing Procedure	
	Appearance : No Abnormalities	Lead Wire or Terminals Shall be Immersed Up to 2 mm form Body (A) Body Diameter ≥ 5 mm : Into The Molten Solder o Which Temperature : 260 (+ 5 / - 0)°C for 3 ±0.5 s	
Soldering Heat Resistance	Capacitance Change : Within ±2.5% or ±0.25 pF, Whichever is Large	 Which Temperature : 260 (+ 5 / - 0)°C for 3 ±0.5 s (B) Body Diameter ≥ 5 mm: Into The Molten Solder of Which Temperature 260 (+5 / -0)°C for 5 to 10 s Then Leave at Standard Test Conditions for 1 to 2 Hours, Then Measured * When Soldering Capacitor With a Soldering Iron, it Should be Performed in Following Conditions. Temperature of Iron-Tip : 350 to 400°C Soldering Iron Wattage : 50 W Maximum Soldering Time : 3.5 seconds Maximum 	
	Withstand Voltage : (Between Terminals) No Abnormalities		
Humidity Characteristic	Appearance : No Abnormalities		
	Capacitance Change : CH : Within $\pm 5\%$ or ± 0.5 pF, Whichever is Large	Capacitors Shall be Subjected to a Relative	
	$ \begin{array}{ c c c } Q \ Factor: CH: Less \ than \ 10 \ pF = > Q \\ \geq 200 \ + \ 10 \ \times \ C \ More \ than \ 10 \ pF \ and \\ Less \ than \ 30 \ pF = > Q \geq 275 \ + \ 5 \ \times \ C/2 \\ More \ than \ 30 \ pF = > Q \geq 350 \end{array} $	Humidity of 90 to 95% at 40 \pm 2°C for 500 (+ 24 / - 0) Hours, Then Dried for 1 to 2 Hours and Measured	
	Insulation Resistance : 1,000 M Ω Min.		
	Appearance : No Abnormalities		
Humidity Loading	Capacitance Change : CH : Within ±7.5% or ±0.75 pF, Whichever is Large	Capacitors Shall be Subjected to a Relative Humidity of 90 to 95% at 40 \pm 2°C for 500 (+24 / -0) Hours with Rated Voltage Applied (Less than 50 mA), than Dried for 1 to 2 Hours and Measured	
Humidity Loading	Q Factor :CH : Less than 30 pF = > Q \ge 100 + 10 × C/3 More than 30 pF = > Q \ge 200		
	Insulation Resistance : 500 M Ω Min.		
High Temperature Loading	Appearance : No Abnormalities	Capacitors Shall be Subjected to a Test of : (A) Below 1 KV: 200% Rated Voltage with 50 mA Maximum	
	Capacitance Change : CH : Within ±3% or ±0.3 pF, Whichever is Large		
	Q Factor : CH : Less than 10 pF = > Q \geq 200 + 10 × C More than 10 pF and Less than 30 pF = > Q \geq 275 + 5 × C/2 More than 30 pF = > Q \geq 350	 (B) 1 KV and above: 150% Rated Voltage with 50 mA Maximum for 1,000 (+48 / -0) Hours at 85°C ±2°C (for CH and SL) and than Dried for 1 to 2 Hours and 	
	Insulation Resistance : 1,000 M Ω Min.	Measured	
	Appearance : No Abnormalities		
Temperature Cycling	Capacitance Change : Within ±5% or ±0.5 pF, Whichever is Large	Capacitors Shall be Subjected to: -25 ±3°C (30 ±3 min) → 25°C (3 min) → 85 ±3°C	
	DF C < 30 pF : Q \ge 275 + (5/2) C C \ge 30 pF : Q \ge 350	$(30 \pm 3 \text{ min}) \rightarrow 25^{\circ}\text{C}$ (3 min) for 5 Cycle	
	Insulation Resistance : 1,000 M Ω Min.		

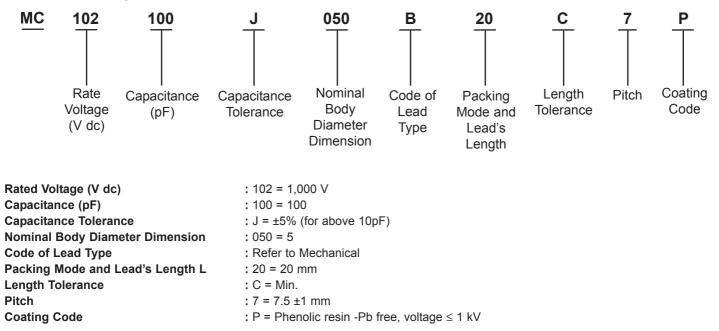




Part Number Table

Description	Part Number		
Ceramic Disc Capacitor, CH	MC102100J050B20C7P		

Part Number Explanation:



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